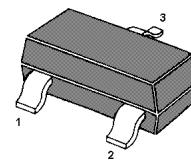


SS8050 TRANSISTOR (NPN)**FEATURES**

Complimentary to SS8550

SOT-23**MARKING: Y1****MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)**

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	40	V
V_{CEO}	Collector-Emitter Voltage	25	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	1.5	A
P_c	Collector Power Dissipation	0.3	W
T_j	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55-150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C= 100\mu\text{A}, I_E=0$	40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C= 0.1\text{mA}, I_B=0$	25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=40\text{V}, I_E=0$			0.1	μA
Collector cut-off current	I_{CEO}	$V_{CB}=20\text{V}, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}= 5\text{V}, I_C=0$			0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE}=1\text{V}, I_C= 100\text{mA}$	200		350	
	$h_{FE(2)}$	$V_{CE}=1\text{V}, I_C= 800\text{mA}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=800\text{mA}, I_B= 80\text{mA}$			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=800\text{mA}, I_B= 80\text{mA}$			1.2	V
Transition frequency	f_T	$V_{CE}=10\text{V}, I_C= 50\text{mA}$ $f=30\text{MHz}$	100			MHz

电话: 0755-82568882 82568883

邮箱: idchip@indreamchip.com

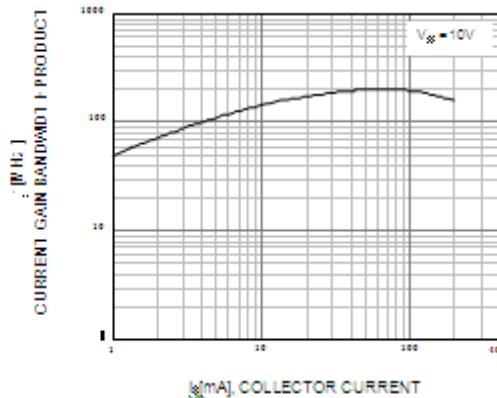
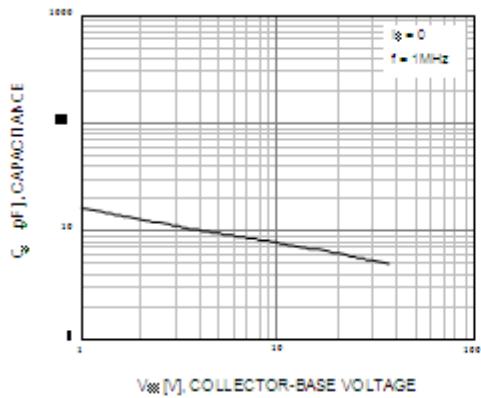
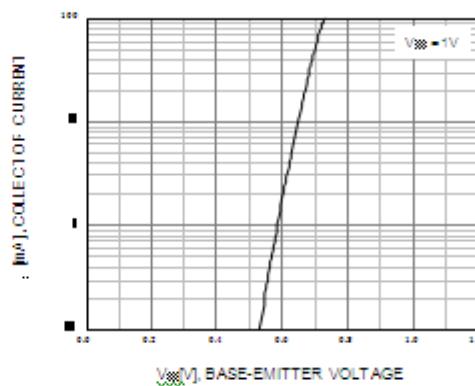
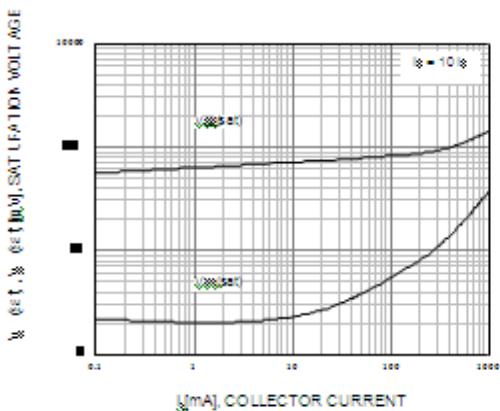
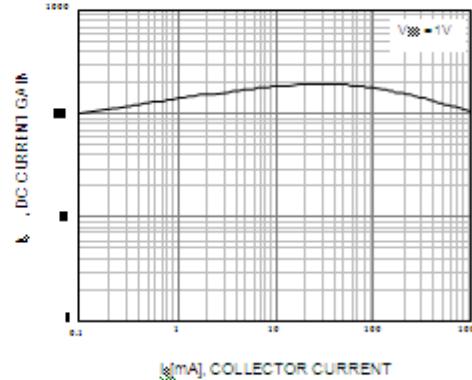
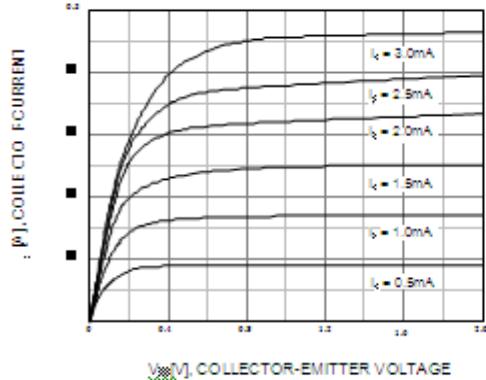
传真: 0755-82568886

网址: www.idchip.cn

公司地址: 深圳市福田区滨河大道联合广场 A 座 1308

Typical Characteristics

SS8050



电话：0755-82568882 82568883

邮箱：idchip@indreamchip.com

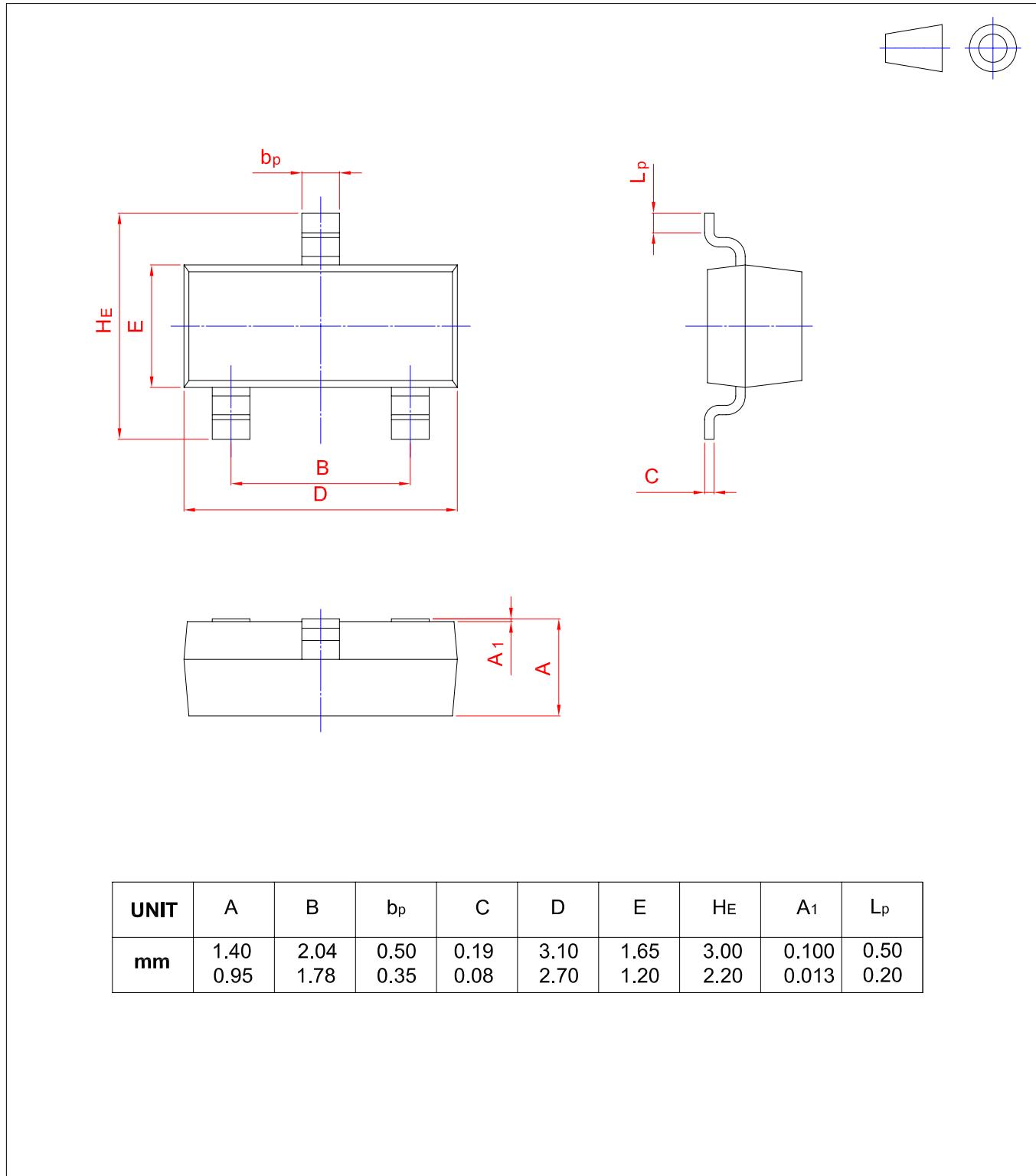
传真：0755-82568886

网址：www.idchip.cn

公司地址：深圳市福田区滨河大道联合广场 A 座 1308

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23

电话: 0755-82568882 82568883

邮箱: idchip@indreamchip.com

传真: 0755-82568886

网址: www.idchip.cn

公司地址: 深圳市福田区滨河大道联合广场 A 座 1308

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by IDCHIP manufacturer:

Other Similar products are found below :

[619691C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [BC557/116](#) [BSW67A](#) [NJVMJD148T4G](#) [NTE123AP-10](#) [NTE153MCP](#) [NTE16](#)
[NTE195A](#) [NTE92](#) [C4460](#) [2N4401-A](#) [2N6728](#) [2SA1419T-TD-H](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [2SC2712S-GR,LF](#) [2SC5488A-TL-H](#)
[2SD2150T100R](#) [SP000011176](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SC2412KT146S](#) [2SD1816S-TL-E](#) [CPH6501-TL-E](#) [MCH4021-TL-E](#)
[MJE340](#) [US6T6TR](#) [NJK0281DG](#) [732314D](#) [CPH3121-TL-E](#) [CPH6021-TL-H](#) [873787E](#) [IMZ2AT108](#) [UMX21NTR](#) [MCH6102-TL-E](#) [FP204-](#)
[TL-E](#) [NJK0302DG](#) [2N3583](#) [2SA2014-TD-E](#) [2SC2812-5-TB-E](#) [30A02MH-TL-E](#) [NSV40301MZ4T1G](#) [NTE13](#) [NTE26](#) [NTE282](#) [NTE323](#)